Hits	Search Text	DB	Time stamp
116541	gasket polytetrafluorethylene	USPAT; US-PGPUB;	2003/05/19 05:01
25	(gasket polytetrafluorethylene) same lossy	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/05/19 05:01
2858366	<pre>(semiconductor processor microprocessor chip die ic (integrated adj circuit))</pre>	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/05/19 05:03
430180	heat with (dissipate sink spreader slug element metal)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/05/19 05:04
420607	eds electrostatic electro-static (electro adj3 static)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/05/19 05:05
26672	(eds electrostatic electro-static (electro adj3 static)) with (discharge discharging)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/05/19 05:05
503	((semiconductor processor microprocessor chip die ic (integrated adj circuit))) and (heat with (dissipate sink spreader slug element metal)) and (eds electrostatic electro-static (electro	USPAT; USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/19 05:05
44	(gasket polytetrafluorethylene) and ((semiconductor processor microprocessor chip die ic (integrated adj circuit))) and (heat with (dissipate sink spreader slug element metal)) and ((eds electrostatic electro-static (electro adj3 static)) with (discharge	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/19 05:24
459	((gasket polytetrafluorethylene) and ((semiconductor processor microprocessor chip die ic (integrated adj circuit))) and (heat with (dissipate sink spreader slug element metal)) and (eds electrostatic electro-static (electro adj3 static))) not ((gasket polytetrafluorethylene) and ((semiconductor processor microprocessor chip die ic (integrated adj circuit))) and (heat with (dissipate sink spreader slug element metal)) and ((eds electrostatic electro-static (electro	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/19 05:24
	116541 25 2858366 430180 420607 26672 503	25   (gasket polytetrafluorethylene)   same   lossy	USPAT: US-PGPUB: EPO; JPO: DERWENT: IBM TDB USPAT: US-PGPUB: EPO

10 127	(((gasket polytetrafluorethylene) and ((semiconductor processor microprocessor chip die ic (integrated adj circuit))) and (heat with (dissipate sink spreader slug element metal)) and (eds electrostatic electro-static (electro adj3 static))) not ((gasket polytetrafluorethylene) and ((semiconductor processor microprocessor chip die ic (integrated adj circuit))) and (heat with (dissipate sink spreader slug element metal)) and ((eds electrostatic electro-static (electro adj3 static)) with (discharge discharging)))) and package	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/19
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